

UNITED STATES PATENT AND TRADEMARK OFFICE
CERTIFICATE OF CORRECTION

PATENT NO. : 6,867,064 B2
DATED : March 15, 2005
INVENTOR(S) : Kristy A. Campbell et al.

Page 1 of 1

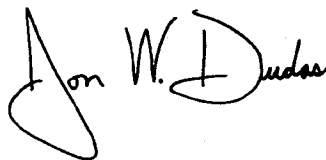
It is certified that error appears in the above-identified patent and that said Letters Patent is hereby corrected as shown below:

Title page.

Item [56], **References Cited**, U.S. PATENT DOCUMENTS, "5,335,519 A 8/1994 Bernie" should read -- 5,335,219 8/1994 Ovshinsky et al. --
OTHER PUBLICATIONS, "El Bouchairi, B.; Bernede, J.C.; reference, "El Bouchairi, B.; Bernede, J.C.; Burgaud, P., Properties of $\text{Ag}_2\text{-xSe}_{1+\text{x/n-Si}}$ diodes, Thin Solid Films 110 (1983) 107-113." should read -- El Bourchairi,B; Bernede, J.C.; Burgaud, P., Properties of $\text{Ag}_2\text{-xSe}_{1+\text{x/n-Si}}$ diodes, Thin Solid Films 110 (1983) 107-113. --
"Feng, X.; Bresser," reference "Feng, X.; Bresser, W.J.; Boolchand, P., Directed evidence for stiffness threshold in Chalcogenide glasses, Phys. Rev. Lett. 78 (1997) 4422-4425." should read -- Feng, X.; Bresser, W.J.; Boolchand, P., Direct evidence for stiffness threshold in chalcogenide glasses, Phys. Rev. Lett. 78 (1997) 4422-4425. --
"Hosokawa, S., reference, " Hosokawa, S., Atomic and electronic structures of glassy GexSe1-x around the stiffness threshold composition, J. Optoelectroncis and Advanced Materials 3 (2001) 199-214." should read -- Hosokawa, S., Atomic and electronic structures of glassy GexSe1-x around the stiffness threshold compositon, J. Optoelectronics and Advanced Materials 3 (2001) 199-214. --
"Mitokova, M.; Wang, Y Boolchand, P.," reference Dual chemical role of Ag as an additive in chalgénide glasses Phys. Rev. Lett. 83 (1999) 3848-3851." should read -- Mitkova, M.; Wang, Y.; Boolchand, P., Dual chemical role of Ag as an additive in chalcogenide glasses, Phys. Rev. Lett. 83 (1999) 3848- 3851. --
"Yoji Kowamoto et al." reference, "Ionic Conduction in $\text{As}_2\text{S}_3\text{-Ag}_2\text{S}$, $\text{GeS}_2\text{Ges-Ag}_2\text{S}$ and $\text{P}_2\text{S}_5\text{-Ag}_2\text{S}$ Glasses," Journal of Non-Crystalline Solids 20 (1976), pgs. 393-404." should read -- Yoji Kawamoto et al.,-"Ionic Conduction in $\text{As}_2\text{S}_3\text{-Ag}_2\text{S}$, $\text{GeS}_5\text{GeS-Ag}_2\text{S}$ and $\text{P}_2\text{S}_5\text{-Ag}_2\text{S}$ Glasses," Journal of Non-Crystalline Solids 20 (1976), pgs. 393-404. --

Signed and Sealed this

Twenty-eighth Day of June, 2005



JON W. DUDAS
Director of the United States Patent and Trademark Office